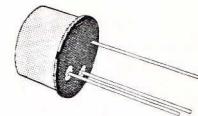


MEDIUM POWER AMPLIFIER

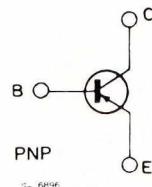
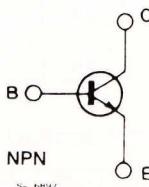
DESCRIPTION

The BC440 and BC441 are silicon planar epitaxial NPN transistors in TO-39 metal case. They are intended for general purpose applications, especially for driver stages.

The complementary PNP types are respectively the BC460 and BC461.



TO-39

INTERNAL SCHEMATIC DIAGRAM

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value		Unit
		BC440	BC441	
V_{CBO}	Collector-base Voltage ($I_E = 0$)	50	70	V
$V_{CEO(sus)}$	Collector-emitter Voltage ($I_B = 0$)	40	60	V
V_{CER}	Collector-emitter Voltage ($R_{BE} \leq 100 \Omega$)	50	70	V
V_{EBO}	Emitter-base Voltage ($I_C = 0$)	5		V
I_{CM}	Collector Peak Current	2		A
P_{tot}	Total Power Dissipation at $T_{amb} \leq 25^\circ\text{C}$ at $T_{case} \leq 25^\circ\text{C}$	1	10	W
T_{stg}	Storage Temperature	- 65 to 200		°C
T_j	Junction Temperature	200		°C

THERMAL DATA

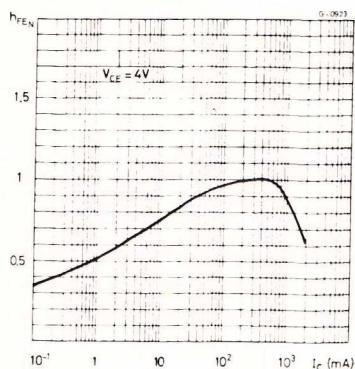
$R_{th\ j\text{-case}}$	Thermal Resistance Junction-case	Max	17.5	$^{\circ}\text{C}/\text{W}$
$R_{th\ j\text{-amb}}$	Thermal Resistance Junction-ambient	Max	175	$^{\circ}\text{C}/\text{W}$

ELECTRICAL CHARACTERISTICS ($T_{case} = 25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Parameter	Test Conditions		Min.	Typ.	Max.	Unit
I_{CBO}	Collector Cutoff Current ($I_E = 0$)	$V_{CB} = 40\text{ V}$				100	nA
I_{CER}	Collector Cutoff Current ($R_{BE} = 100\ \Omega$)	For BC440 For BC441	$V_{CE} = 50\text{ V}$ $V_{CE} = 70\text{ V}$			10 10	μA μA
$V_{(BR)\ EBO}$	Emitter Base Breakdown Voltage ($I_C = 0$)	$I_E = 100\ \mu\text{A}$		5			V
$V_{(BR)\ CEO}^*$	Collector-emitter Breakdown Voltage ($I_B = 0$)	$I_C = 10\text{ mA}$	For BC440 For BC441	40 60			V V
$V_{CE\ (\text{sat})}^*$	Collector-emitter Saturation Voltage	$I_C = 1\text{ A}$	$I_B = 100\text{ mA}$			1	V
$V_{BE\ (\text{sat})}$	Base-emitter Saturation Voltage	$I_C = 1\text{ A}$	$I_B = 100\text{ mA}$			1.5	V
h_{FE} *	DC Current Gain Gr. 4 Gr. 5 Gr. 6	$I_C = 500\text{ mA}$ $V_{CE} = 4\text{ V}$ $I_C = 500\text{ mA}$ $V_{CE} = 4\text{ V}$ $I_C = 500\text{ mA}$ $V_{CE} = 4\text{ V}$ $I_C = 1\text{ A}$ $V_{CE} = 2\text{ V}$ (for BC440 only)		40 60 115 20		70 130 250	
f_T	Transition frequency	$I_C = 50\text{ mA}$	$V_{CE} = 4\text{ V}$	50			MHz

* Pulsed : pulse duration = 300 μs , duty cycle = 1 %.

DC Normalized Current Gain.



Collector-emitter Saturation Voltage.

